Hall Eff	feet in p	en in	4/12	X FY Dov	yne w	Jong	
Premne/t 8.4±0.1	/	/	B [Im -21, 23±0,02 m]	35	₩ _H /V .85±0.P1 2.5V)	J	supe
(4.510.1	0.95±0.05	-0.55+0.	- 40.0 ±0.1 m]	×+ (2.	5V) (05±0,01)	same	Yom
14.6 to .1	0,9120.05	(250 V)	(-36.6 to.1m) -24.88 to.2m7	0,2010;010:01	71±0.01	Same	BOMV

	19.7+0.1	Mex Jancary
	0,9240,05	>
	(250X)	
-36.6 to. 1	- 33.9 to.1	B/mT revene
-24.64+0.02	(27,75,502)	1 Im forward
0.20105	0.10 to.05	Im/Amp
	10.0756.1-	VH DO
	rend: 2.2ku States 2.5 kv	highvolterse
	KOMV	hothe on

HAL	4/13	Opression (re: 20,010 Sefore Id, Vd		Input high wol 2.5kV; rea	
B/mT I Grund / 7 measure on formas -28.9±0.1	I revene -33.8 ±		Id/mA Z 09±002	Vd / 50±	V _H /V -2.3±0.1	noile on sope (ptp) dom V
-17.1~	-45,2±0	0.3+0.07	0.85±0.0	2 52 2	-4.570,2	Somv
-2.6	-61.8	1.0540.01	0.85to.2	-52±7	-5.1to.2	80mV
-24.4	-39.3	0.3 ±0.01	U.87 too7	-57±2	-4.350.2	60mV
-8.7	-54.8	1.85±0.01	0.87 Lv.02	- 51±2	-5.9tu.2	50nV
4/15	Pressure:	25.0±0.160m	lapat h	igh voltage:	2.tkV, ned	2.2kV
-29.0	-33.6	0.12002	0.63	-60	-2.3	60mV
- 24.65 to.00	-10	0.2	0.64	- 80	-3.7	FOMV
-21.90	-39.6	0,3	0.62	-60	-4.0	FOMV
-19.4	-42.5	0.4	0.39	-63	- 3.8	FONV
- 16.3	-45.2	0.5	0.57	-62	- 4.8	SUMV
-13. Z	-48.6	0-65	0.35	-58	-4.8	80 mV
-11.9	-51.1	0.7	0.35	-60	- 4.9	80mV
						n n dH AH

A		OPTESS V	re: 15.010	ybrr high	witege: 2.15 kV	; read 2.3kl
B/mT	Trevene	Im/Amp	Id/MA	Va/V	VH/V	noill on supp
I Gomend	-34.4	0.1	1.60	-42	-4.5	400V
-29.0 -24.4	- 37.5	0.2	1.61	-42	-4.9	3020
-21.8	-40.J-	0,3	1.61	- 39	- 4.8	30mV
4/18		0.4	1.80	- 38	-4.77	SomV
-18.9	-43.2	0.5		Jo	•	
-16.6	-45.9					
20.0±0.	- 36.9	0.2	1.34	-46	-4.2	40mV
-27.1	-42.8	0.4	1.33		- 5.8	4UNV
-19.8 -13.5	-48.4	0.6	1.32	-49 -	-5.9	Yunv
-11.0	- 51.6	0.7	1.32	-49 -	6.2	KunV
-4.50	-59.1-	0.95	1.31	-4g -	6.8	45mV
	•					